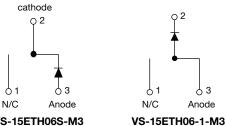
SHA www.vishay.com

VS-15ETH06S-M3, VS-15ETH06-1-M3

Vishay Semiconductors

Hyperfast Rectifier, 15 A FRED Pt[®]

2 3 **TO-262AA** D²PAK (TO-263AB) Base



VS-15ETH06S-M3

| PRIMARY CHARACTE | RISTICS |
|----------------------------------|---|
| I _{F(AV)} | 15 A |
| V _R | 600 V |
| V _F at I _F | 1.3 V |
| t _{rr} (typ.) | 22 ns |
| T _J max. | 175 °C |
| Package | D ² PAK (TO-263AB), TO-262AA |
| Circuit configuration | Single |

FEATURES

- · Hyperfast recovery time
- · Low forward voltage drop
- · Low leakage current
- 175 °C operating junction temperature
- · Single die center tap module
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

| ABSOLUTE MAXIMUM RATINGS | | | | | | |
|---|-----------------------------------|-------------------------|-------------|-------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MAX. | UNITS | | |
| Peak repetitive reverse voltage | V _{RRM} | | 600 | V | | |
| Average rectified forward current | I _{F(AV)} | T _C = 140 °C | 15 | | | |
| Non-repetitive peak surge current | I _{FSM} | T _J = 25 °C | 120 | A | | |
| Peak repetitive forward current | I _{FM} | | 30 | | | |
| Operating junction and storage temperatures | T _J , T _{Stg} | | -65 to +175 | °C | | |

| ELECTRICAL SPECIFIC | $T_{\rm J} = 150 ^{\circ}{\rm C}, V_{\rm R} = V_{\rm R} \text{rated}$ - 30 500 | | | | | |
|--|--|--|-----|-----|--|----|
| PARAMETER | SYMBOL | $\begin{tabular}{ c c c c c c c } \hline TEST CONDITIONS & MIN. & TYP. & MAX. & UNITS \\ \hline I_R = 100 \ \mu A & 600 & - & - & \\ \hline I_F = 15 \ A & - & 1.8 & 2.2 & \\ \hline I_F = 15 \ A, \ T_J = 150 \ ^{\circ}C & - & 1.3 & 1.6 & \\ \hline V_R = V_R \ rated & - & 0.2 & 50 & \\ \hline T_J = 150 \ ^{\circ}C, \ V_R = V_R \ rated & - & 30 & 500 & \\ \hline V_R = 600 \ V & - & 20 & - & pF & \\ \hline \end{tabular}$ | | | | |
| Breakdown voltage, blocking voltage | V _{BR} , V _R | I _R = 100 μA | 600 | - | - | |
| | V | I _F = 15 A | - | 1.8 | 2.2 | V |
| Forward voltage | ۷F | I _F = 15 A, T _J = 150 °C | - | 1.3 | 1.8 2.2 1.3 1.6 0.2 50 | |
| Reverse leakage current | I_ | $V_R = V_R$ rated | - | 0.2 | 50 | |
| Reverse leakage current | IR | $T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$ | - | 30 | 500 | μΑ |
| Junction capacitance | CT | V _R = 600 V | - | 20 | - | pF |
| Series inductance | L _S | Measured lead to lead 5 mm from package body | - | 8.0 | - | nH |

RoHS COMPLIANT

HALOGEN FREE

1



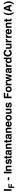
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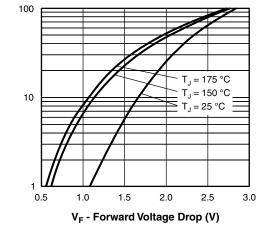
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| DYNAMIC RECOVERY | CHARACT | ERISTICS (T _C = 25 | 5 °C unless otherwis | e specifie | ed) | | |
|--------------------------|------------------|---|---|------------|------|------|--------------------------|
| PARAMETER | SYMBOL | TEST CO | NDITIONS | MIN. | TYP. | MAX. | UNITS |
| | | I _F = 1 A, dI _F /dt = 1 | 00 A/µs, V _R = 30 V | - | 22 | 30 | |
| Reverse recovery time | + | I _F = 15 A, dI _F /dt = | 100 A/µs, V _R = 30 V | - | 28 | 35 | |
| Reverse recovery time | t _{rr} | T _J = 25 °C | | - | 29 | - | 115 |
| | | T _J = 125 °C | I _F = 15 A dI _F /dt = 200 A/μs V _B = 390 V | - | 75 | - | |
| Deels receiver a current | 1 | T _J = 25 °C | | - | 3.5 | - | - A |
| Peak recovery current | IRRM | T _J = 125 °C | | - | 7 | - | A |
| | | T _J = 25 °C | | - | 57 | - | ns Α μC ns Α |
| Reverse recovery charge | Q _{rr} | T _J = 125 °C | | - | 300 | - | μΟ |
| Reverse recovery time | t _{rr} | | I _F = 15 A | - | 51 | - | ns |
| Peak recovery current | I _{RRM} | T _J = 125 °C | dI _F /dt = 800 A/µs | - | 20 | - | А |
| Reverse recovery charge | Q _{rr} | | V _R = 390 V | - | 580 | - | nC |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | | |
|---|-----------------------------------|---|--------------|------|------------|------------------------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | | |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -65 | - | 175 | °C | | |
| Thermal resistance, junction to case per leg | R _{thJC} | | - | 1.0 | 1.3 | | | |
| Thermal resistance, junction to ambient per leg | R _{thJA} | Typical socket mount | - | - | 70 | 20 °C/W | | |
| Thermal resistance, case to heatsink | R _{thCS} | Mounting surface, flat, smooth, and greased | - | 0.5 | - | | | |
| W/oight | | | - | 2.0 | - | g | | |
| Weight | | | - | 0.07 | - | oz. | | |
| Mounting torque | | | 6.0 (5.0) | - | 12 (10) | kgf · cm (lbf · in) | | |
| Marking daying | | Case style D ² PAK (TO-263AB) | | 15ET | H06S | | | |
| Marking device | | Case style TO-262AA | | 15ET | H06-1 | | | |







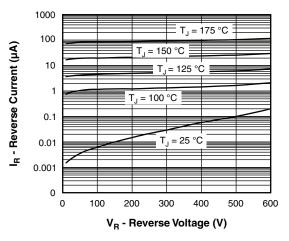


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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VS-15ETH06S-M3, VS-15ETH06-1-M3

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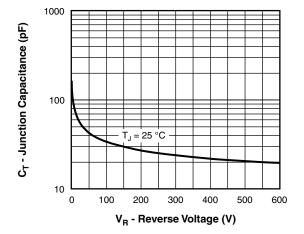


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

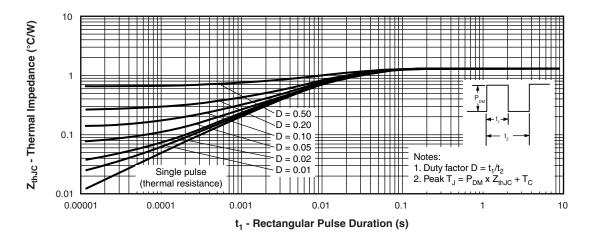
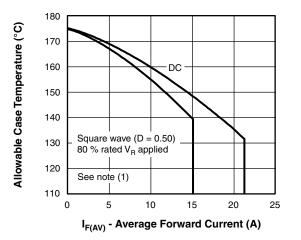
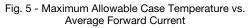


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics





Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 6); Pd_{REV} = inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = rated V_R

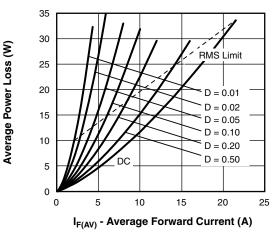


Fig. 6 - Forward Power Loss Characteristics

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VS-15ETH06S-M3, VS-15ETH06-1-M3



Vishay Semiconductors

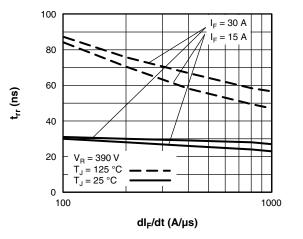


Fig. 7 - Typical Reverse Recovery vs. dl_F/dt

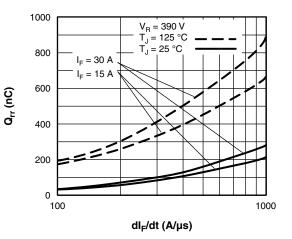


Fig. 8 - Typical Stored Charge vs. dl_F/dt

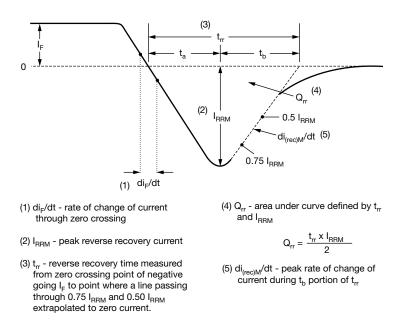


Fig. 9 - Reverse Recovery Waveform and Definitions



Vishay Semiconductors

ORDERING INFORMATION TABLE

www.vishay.com

SHAY

| Device code | vs- | 15 | Е | т | н | 06 | S | TRL | -M3 |
|-------------|------------|-------|-------------------------------|-------------------------------------|---------|-----------|-----------|----------------------|---------|
| | | (2) | (3) | 4 | (5) | 6 | (7) | (8) | (9) |
| | 1 - 2 - | | - | niconduo ng (15 A | | oduct | | | |
| | 3 - | E = | single o | liode | | | | | |
| | 4 - 5 - | | | , D ² PAł ist rectifi | | 63AB) | | | |
| | 6 - | | • • | ng (06 = | |) | | | |
| | 7 - | | = D ² PA = TO-2 | K (TO-2 | 63AB) | | | | |
| | 8 - | | | 62ΑΑ be (50 μ | oieces) | | | | |
| | | | - | | - | | | PAK (T | |
| | | | | | | nt orient | ed, for l | D ² PAK (| (TO-263 |
| | 9 - | - Env | ironmer | ntal digit: | | | | | |

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|---------------|------------------------------------|--|--|--|--|
| PREFERRED P/N | BASE QUANTITY | PACKAGING DESCRIPTION | | | | |
| VS-15ETH06S-M3 | 50 | Antistatic plastic tubes | | | | |
| VS-15ETH06STRR-M3 | 800 | 13" diameter plastic tape and reel | | | | |
| VS-15ETH06STRL-M3 | 800 | 13" diameter plastic tape and reel | | | | |
| VS-15ETH06-1-M3 | 50 | Antistatic plastic tubes | | | | |

| LINKS TO RELATED DOCUMENTS | | | | | | | |
|----------------------------|-------------------------------|--------------------------|--|--|--|--|--|
| Dimensions | D ² PAK (TO-263AB) | www.vishay.com/doc?96164 | | | | | |
| Dimensions | TO-262 | www.vishay.com/doc?96165 | | | | | |
| Part marking information | D ² PAK (TO-263AB) | www.vishay.com/doc?95444 | | | | | |
| Fart marking information | TO-262 | www.vishay.com/doc?95443 | | | | | |
| Packaging information | | www.vishay.com/doc?96424 | | | | | |
| SPICE model | | www.vishay.com/doc?96617 | | | | | |

Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



| ota | ted | 90 | °C |
|----------|------|-------------|----|
| <u>S</u> | cale | <u>ə:</u> 8 | :1 |

| SYMBOL | MILLIM | ETERS | INC | HES | NOTES | |
|--------|--------|-------|-----------|-------|-------|--|
| STMBOL | MIN. | MAX. | MIN. MAX. | | NOTES | |
| А | 4.06 | 4.83 | 0.160 | 0.190 | | |
| A1 | 0.00 | 0.254 | 0.000 | 0.010 | | |
| b | 0.51 | 0.99 | 0.020 | 0.039 | | |
| b1 | 0.51 | 0.89 | 0.020 | 0.035 | 4 | |
| b2 | 1.14 | 1.78 | 0.045 | 0.070 | | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 | |
| с | 0.38 | 0.74 | 0.015 | 0.029 | | |
| c1 | 0.38 | 0.58 | 0.015 | 0.023 | 4 | |
| c2 | 1.14 | 1.65 | 0.045 | 0.065 | | |
| D | 8.51 | 9.65 | 0.335 | 0.380 | 2 | |

| SYMBOL | MILLIM | ETERS | INCHES | | NOTES | |
|--------|--------|-------|----------|-------|-----------|-------|
| | STWBOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| | D1 | 6.86 | 8.00 | 0.270 | 0.315 | 3 |
| | E | 9.65 | 10.67 | 0.380 | 0.420 | 2, 3 |
| | E1 | 7.90 | 8.80 | 0.311 | 0.346 | 3 |
| | е | 2.54 | 2.54 BSC | | 0.100 BSC | |
| | Н | 14.61 | 15.88 | 0.575 | 0.625 | |
| | L | 1.78 | 2.79 | 0.070 | 0.110 | |
| | L1 | - | 1.65 | - | 0.066 | 3 |
| | L2 | 1.27 | 1.78 | 0.050 | 0.070 | |
| | L3 | 0.25 | BSC | 0.010 | BSC | |
| | L4 | 4.78 | 5.28 | 0.188 | 0.208 | |

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Datum A and B to be determined at datum plane H

(6) Controlling dimension: inches

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

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1

Document Number: 96164

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Outline Dimensions



Vishay Semiconductors

TO-262AA

DIMENSIONS in millimeters and inches





F D1 (3) (3) Section A - A Base (4) Plating b1. b3 metal ≰ c1 (4) -(b, b2)-Section B - B and C - C Scale: None





Diodes 1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode

Lead assignments

| CVMPOI | MILLIN | IETERS | INC | HES | 10770 |
|--------|--------|--------|-------|-------|-------|
| SYMBOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| А | 4.06 | 4.83 | 0.160 | 0.190 | |
| A1 | 2.03 | 3.02 | 0.080 | 0.119 | |
| b | 0.51 | 0.99 | 0.020 | 0.039 | |
| b1 | 0.51 | 0.89 | 0.020 | 0.035 | 4 |
| b2 | 1.14 | 1.78 | 0.045 | 0.070 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 |
| С | 0.38 | 0.74 | 0.015 | 0.029 | |
| c1 | 0.38 | 0.58 | 0.015 | 0.023 | 4 |
| c2 | 1.14 | 1.65 | 0.045 | 0.065 | |
| D | 8.51 | 9.65 | 0.335 | 0.380 | 2 |
| D1 | 6.86 | 8.00 | 0.270 | 0.315 | 3 |
| E | 9.65 | 10.67 | 0.380 | 0.420 | 2, 3 |
| E1 | 7.90 | 8.80 | 0.311 | 0.346 | 3 |
| е | 2.54 | BSC | 0.100 |) BSC | |
| L | 13.46 | 14.10 | 0.530 | 0.555 | |
| L1 | - | 1.65 | - | 0.065 | 3 |
| L2 | 3.56 | 3.71 | 0.140 | 0.146 | |

 ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the second dimensioner of the second dimensis of the second dimensioner of the second dimensioner of the the outmost extremes of the plastic body (3)

Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only (5)

Controlling dimension: inches

(6) Outline conform to JEDEC® TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), L1 (max.), L2 (min., max.)

Revision: 30-Nov-17

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